

Effect of chemical substitution and pressure on YbRh_2Si_2

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We carried out electrical resistivity experiments on $(\text{Yb,L a})\text{Rh}_2\text{Si}_2$ and on $\text{Yb}(\text{Rh,I r})_2\text{Si}_2$ under pressure and in magnetic fields. YbRh_2Si_2 exhibits a weak antiferromagnetic transition at atmospheric pressure with a Néel temperature of only $T_N \approx 70$ mK. By applying a small magnetic field T_N can be continuously suppressed to $T = 0$ at $B_c = 60$ mT ($B \perp c$) driving the system to a quantum critical point (QCP). On applying external pressure the magnetic phase is stabilized and $T_N(p)$ is increasing as usually observed in Yb-based heavy-fermion metals.

Substituting Yb by La or Rh by Ir allows to create a negative chemical pressure, La (Ir) being smaller than Yb (Rh), and eventually to drive YbRh_2Si_2 to a pressure controlled QCP. In this paper we compare the effect of external hydrostatic pressure and chemical substitution on the ground-state properties of YbRh_2Si_2 .

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1 Introduction New unconventional states are emerging in the vicinity of quantum critical points (QCP), where critical quantum fluctuations determine the low-temperature properties. Heavy-fermion (HF) metals are ideal model systems to study quantum-critical behavior. External pressure, chemical substitution, or magnetic field allow to tune the ground state properties. If a magnetically ordered state is suppressed continuously to zero temperature, eventually a QCP is reached. In Ce-based HF metals application of external pressure suppresses magnetism, while in Yb-based materials magnetism is stabilized.

YbRh_2Si_2 orders antiferromagnetically at a Néel temperature of only $T_N \approx 70$ mK [1]. T_N can be suppressed to zero temperature by applying a small magnetic fields at a critical field B_{c0} of about 0.06 and 0.66 T for $B \perp c$ and $B \parallel c$, respectively. In the vicinity B_{c0} pronounced non-Fermi liquid behavior is observed [2]. The QCP in most HF systems is of 3 dimensional spin-density wave (conventional) type. At a conventional QCP the quasiparticles formed by the $4f$ electrons and the conduction electrons stay intact. Recently, the discovery of an unconventional QCP in YbRh_2Si_2 attracted special attention [3,4]. In YbRh_2Si_2 it is discussed that the quasiparticles de-

compose at the QCP. This is related to a break down of the Kondo effect, introducing an additional energy scale, $T^*(B)$. The break down of the Kondo effect is reflected in a change of the Fermi volume, which has been inferred from results of the Hall coefficient, ac-susceptibility, specific heat, magnetostriction, and magnetoresistance [4, 5]. Here, we present a substitution and pressure study of YbRh_2Si_2 .

2 Experimental Details Single crystals of $\text{Yb}_{1-x}\text{La}_x\text{Rh}_2\text{Si}_2$ ($x = 0.05$ and 0.1) and of $\text{Yb}(\text{Rh}_{1-y}\text{Ir}_y)_2\text{Si}_2$ ($y = 0.06$) were grown in In-flux. The ThCr_2Si_2 structure was confirmed by X-ray powder diffraction using ground single crystalline material. The stoichiometry of the samples was verified using energy dispersive X-ray analysis (EDX). Electrical resistivity (ρ) measurements under hydrostatic pressure (p) have been carried out by a standard four-probe technique. In different piston-cylinder type cells pressure up to 2.5 GPa was generated. The shift of the superconducting transition temperature of lead (tin) under pressure served as pressure gauge. In a ^3He - ^4He dilution cryostat equipped with a superconducting magnet

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temperatures down to 50 mK and magnetic fields up to 8 T could be reached.

3 Results and Discussion The temperature–pressure ($T - p$) phase diagram of Yb_{1-x}La_xRh₂Si₂ and Yb(Rh_{1-y}Ir_y)₂Si₂ was determined by electrical resistivity experiments. At ambient pressure none of the investigated samples, Yb_{1-x}La_xRh₂Si₂ ($x = 0.05$ and 0.1) and Yb(Rh_{1-y}Ir_y)₂Si₂ ($y = 0.06$), shows the onset of magnetic order down to $T = 50$ mK. Both La- and Ir-substitution are expanding the crystal lattice leading to a negative chemical pressure and, therefore, are expected to suppress the magnetism observed in YbRh₂Si₂. Replacing 5% (10%) Yb by La expands the unit cell volume by about $\sim 0.2\%$ ($\sim 0.4\%$). Using the bulk modulus of YbRh₂Si₂, $B = 187$ GPa [6], as an approximation for the substituted compounds, the hypothetical (negative) pressure corresponding to the lattice expansion can be calculated as $\Delta p = -(B/V)\Delta V$, where V is the unit-cell volume. For $x = 0.05$ ($x = 0.1$) a corresponding pressure $\Delta p = -0.35$ GPa ($\Delta p = -0.67$ GPa) is obtained. In the same way in Yb(Rh_{1-y}Ir_y)₂Si₂ the substitution of Rh by Ir, $y = 0.06$, expands the lattice by $\sim 0.03\%$ which corresponds to $\Delta p = -0.06$ GPa.

The resistivity of the La- and Ir-substituted YbRh₂Si₂ exhibits the typical temperature dependence of a Kondo-lattice system. At ambient pressure $\rho(T)$ shows a clear maximum around $T_M \approx 143$ K for both La substituted compounds [9], while $T_M \approx 130$ K for the 6% Ir substituted sample [10]. Below T_M $\rho(T)$ decreases strongly due to the onset of coherent Kondo scattering. With increasing pressure $T_M(p)$ shifts to lower temperatures with an initial rate of about $dT_M/dp|_{p=0} \approx -31$ K/GPa for the La-substituted samples and $dT_M/dp|_{p=0} \approx -46$ K/GPa for Yb(Rh_{0.94}Ir_{0.06})₂Si₂. These values are comparable with the one found in YbRh₂Si₂ [7]. $T_M(p)$ can be taken as a measure of the pressure dependence of the Kondo temperature. Therefore, a decreasing T_M evidences a weakening of the Kondo-interactions. In other words, the system is moved toward magnetism by application of pressure, as it is expected in a simple Doniach picture for Yb-based HF metals.

At ambient pressure $\rho(T)$ of the investigated Yb_{1-x}La_xRh₂Si₂ samples shows a quasi-linear temperature dependence [11]. This behavior is also observed in the low pressure range. In YbRh₂Si₂ a clear drop of the resistance is observed at $T_N \approx 70$ mK [1]. For neither of the two different Yb_{1-x}La_xRh₂Si₂ concentrations a similar drop is observable in the pressure range, where it would be expected according to our previous considerations. In a more detailed analysis, however, $d\rho/dT$ shows a broad feature indicating T_N . T_N is taken as the temperature where the derivative changes its curvature. In Yb_{0.95}La_{0.05}Rh₂Si₂ it is first observed at $p = 0.95$ GPa at $T_N = 0.19$ K. With further increasing pressure $T_N(p)$ shifts to higher temperatures. At 1.62 GPa a second fea-

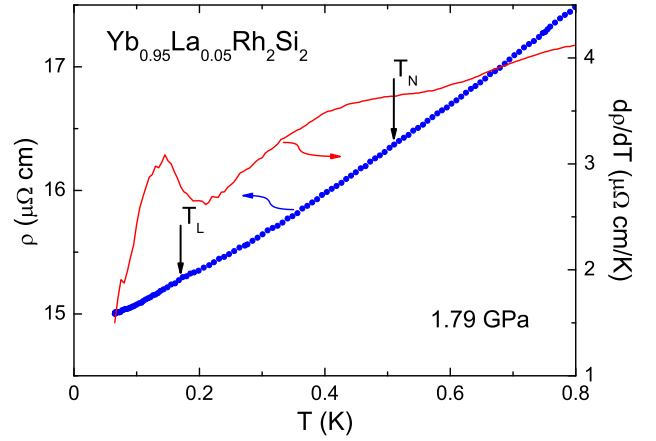


Figure 1 $\rho(T)$ (left axis) and $d\rho(T)/dT$ (right axis) of Yb_{0.95}La_{0.05}Rh₂Si₂ at $p = 1.79$ GPa. The arrows indicate T_N and T_L , respectively.

ture at $T_L < T_N$ is observed in $d\rho/dT$ which is also visible as a small drop in $\rho(T)$. Figure 1 displays $\rho(T)$ and its derivative at $p = 1.79$ GPa. The kink at T_L corresponds to a second magnetic transition below T_N which has been also reported in YbRh₂Si₂ under pressure [7]. The transition at T_L has been assigned to a reorientation of the magnetic moments. The reason for the very weak feature of the magnetic transition in the resistivity data of La-substituted YbRh₂Si₂ might be related to the relatively high value of the residual resistivity, ρ_0 , compared with YbRh₂Si₂. However, in Yb(Rh_{0.94}Ir_{0.06})₂Si₂ at $p = 0.46$ GPa the transition at T_N is clearly visible (see Fig. 2) with a residual resistivity comparable with

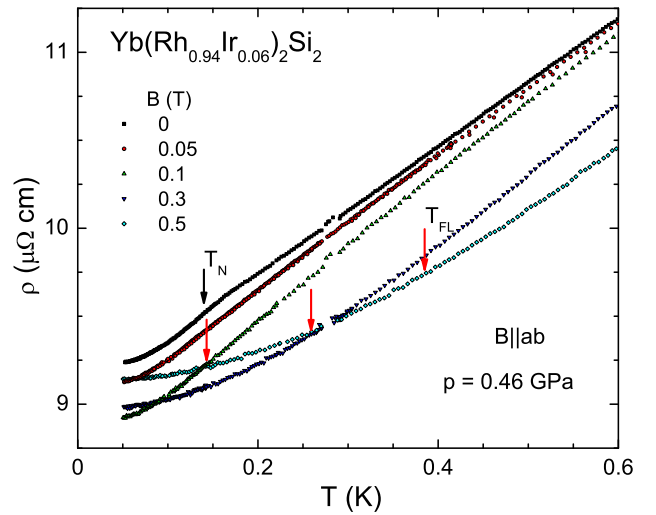


Figure 2 $\rho(T)$ of Yb(Rh_{0.94}Ir_{0.06})₂Si₂ at $p = 0.46$ GPa in different magnetic fields. The arrow indicates the Néel transition at $B = 0$. At $B = 0.1, 0.3$ and 0.5 T the Fermi-liquid crossover temperature T_{FL} is marked by arrows.

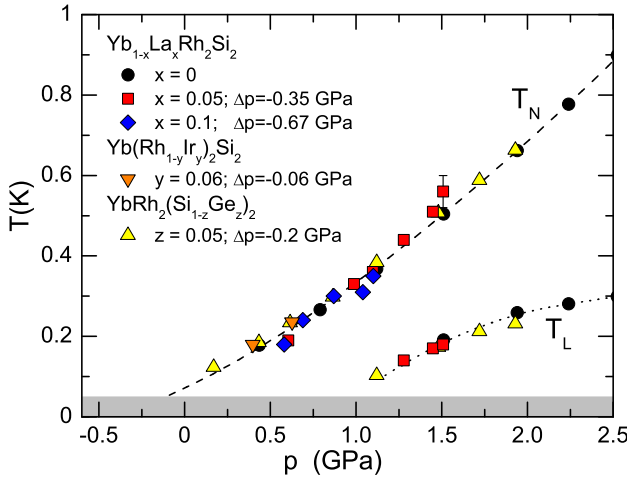


Figure 3 $p - T$ phase diagram of YbRh_2Si_2 summarizing the pressure studies on the La, Ir, and Ge substituted samples. The data of the substituted samples are shifted on the pressure axis with respect to pure YbRh_2Si_2 according to the pressure shift given in the figure. For $\text{Yb}_{0.95}\text{La}_{0.05}\text{Rh}_2\text{Si}_2$ a representative error bar is given for T_N ; for T_L the symbol size is larger than the error. Data on YbRh_2Si_2 and $\text{YbRh}_2(\text{Si}_{0.95}\text{Ge}_{0.05})_2$ were taken from Ref. [7] and the data on $\text{Yb}_{0.9}\text{La}_{0.1}\text{Rh}_2\text{Si}_2$ from Ref. [8]. See text for details.

that of the 10% La substituted sample. Furthermore, at higher pressures both magnetic transitions at T_N and T_L are visible as two successive kinks in $\rho(T)$ [10].

The $p - T$ phase diagram presented in Fig. 3 summarizes the pressure studies on $\text{Yb}_{1-x}\text{La}_x\text{Rh}_2\text{Si}_2$ and $\text{Yb}(\text{Rh}_{1-y}\text{Ir}_y)_2\text{Si}_2$. Additionally, data obtained on YbRh_2Si_2 and $\text{YbRh}_2(\text{Si}_{1-z}\text{Ge}_z)_2$ are included [7]. $T_N(p)$ and $T_L(p)$ for the corresponding samples are shifted according to the effective chemical pressure, which has been calculated as explained before. As a result $T_N(p)$ and $T_L(p)$, respectively, fall each on one single line evidencing the existence of a generalized $p - T$ phase diagram. This highlights a close correspondence between chemical pressure and external pressure.

In the following, we will discuss the $B - T$ phase diagram of $\text{Yb}(\text{Rh}_{0.94}\text{Ir}_{0.06})_2\text{Si}_2$ and its pressure evolution. At atmospheric pressure no magnetic order is found down to 20 mK [12]. An extrapolation from our pressure experiments gives a value of about $T_N \approx 20$ mK [10], consistent with the results of the experiments at ambient pressure. A pressure of $p = 0.46$ GPa moves the T_N up to 0.14 K, which is twice as large as T_N of YbRh_2Si_2 . Figure 2 displays the low temperature resistivity of $\text{Yb}(\text{Rh}_{0.94}\text{Ir}_{0.06})_2\text{Si}_2$ at $p = 0.46$ GPa for different magnetic fields ($B \perp c$). At $B = 0$ a clear drop in $\rho(T)$ indicates T_N . In a field of $B = 0.05$ T no feature in $\rho(T)$ is visible anymore. From a simple comparison with YbRh_2Si_2 one would expect a critical field $B_c \approx 100$ mT.

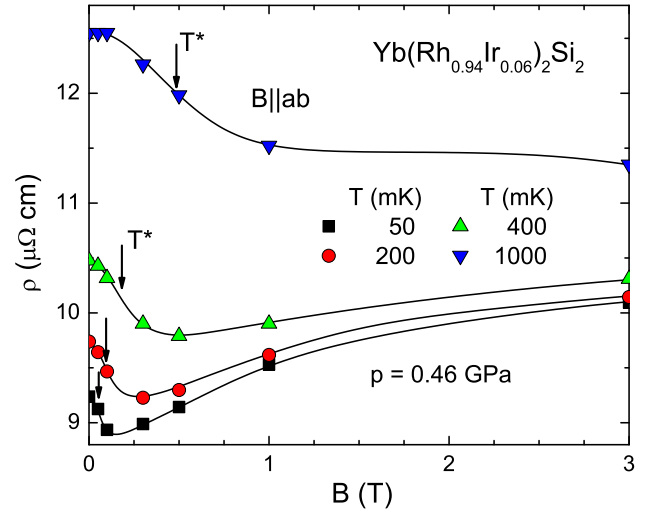


Figure 4 $\rho(H)$ of $\text{Yb}(\text{Rh}_{0.94}\text{Ir}_{0.06})_2\text{Si}_2$ at an external pressure $p = 0.46$ GPa for selected temperatures deduced from the data presented in Fig. 2. The lines are guides to the eye. The arrows indicate T^* .

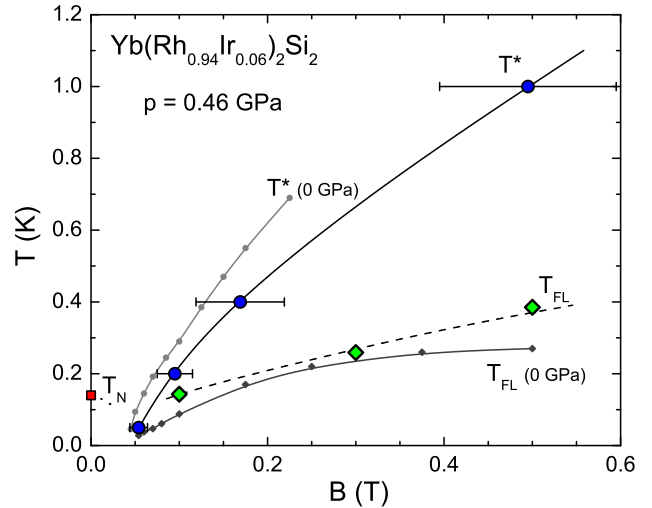


Figure 5 $B - T$ phase diagram of $\text{Yb}(\text{Rh}_{0.94}\text{Ir}_{0.06})_2\text{Si}_2$ at $p = 0.46$ GPa. Additionally, data at $p = 0$ is included [13].

By contrast, our results suggest that T_N is already suppressed to $T < 50$ mK at 50 mT. In magnetic fields $B \geq 0.1$ T, $\Delta\rho \propto T^2$ below the crossover temperature T_{FL} indicates Landau Fermi liquid behavior. Figure 4 shows ρ as a function of the magnetic field. The $\rho(B)$ data was extracted from the temperature dependent measurements displayed in Fig. 2. At all investigated temperatures ($T \leq 1$ K) $\rho(B)$ initially decreases showing a step-like behavior. At ambient pressure in YbRh_2Si_2 [5], as well as in $\text{Yb}(\text{Rh}_{0.94}\text{Ir}_{0.06})_2\text{Si}_2$ [13], the inflection points of the magnetoresistance measured at different temperatures fall on the same $T^*(B)$ line determined from the magnetostric-

tion, magnetization, ac-susceptibility, and Hall effect and ascribed to the Kondo-breakdown crossover. Thus, we take the inflection point of $\rho(B)$ to determine $T^*(B)$. The resulting $B - T$ phase diagram is shown in Fig. 5. Within the error bars the $T^*(B)$ line at atmospheric pressure [13] and at $p = 0.46$ are in reasonable agreement. This holds true also for the Fermi-liquid crossover $T_{FL}(B)$. Our results suggest the existence of a Kondo breakdown also in Yb(Rh_{0.94}Ir_{0.06})₂Si₂ under pressure. Further investigations have to be carried out to clarify the details of the phase diagram.

4 Summary We could show that substitution of YbRh₂Si₂ by small amounts of La, Ir, and Ge in general acts as negative chemical pressure. We could further establish a generalized phase diagram with the unit-cell volume as the only free parameter. In the $B - T$ phase diagram of Yb(Rh_{0.94}Ir_{0.06})₂Si₂ at $p = 0.46$ GPa we could establish the existence of the $T^*(B)$ line.

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